

Fig. 2. The transmission and emission spectra of defect DFB laser films folded on (a) THV and (b) SAN25 at different temperatures. (c) The peak lasing wavelength as a function of temperature for defect DFB lasers folded on (blue circles) THV and (red diamonds) SAN25. The solid lines are linear fits to the experimental data.

with the absorption band of R6G. An Ocean Optics USB 4000 spectrometer records the lasing wavelength(s) of the multilayer laser films and the transmission spectrum of the multilayer films at different temperatures.

3. Results and modeling parameters

3.1. Defect DFB lasers

Figure 2 shows sample reflection and emission spectra from a defect DFB laser folded onto (a) the THV side and (b) the SAN25 side, respectively. The corresponding temperature shifts of the peak lasing wavelength are shown in Fig. 2(c). The emission wavelength, λ_e , at room temperature and the peak laser wavelength's temperature coefficient, $(1/\lambda_e)d\lambda_e/dT$, (T is the temperature) are given in Table 1.

We note that when the reflection band defect is near the short wavelength bandedge (as seen for the sample folded on the SAN25 center layer), the lasing wavelength's temperature coefficient is noticeably smaller than when the reflection band defect is nearer the long wavelength bandedge (as for the sample folded on the THV side). As further discussed below, the initial defect locations imply that the optical thickness of the center SAN25 layer is less than the average optical thickness of the constituent bilayers, whereas the optical thickness of the center THV layer is greater than the average optical thickness of the constituent bilayers [5].

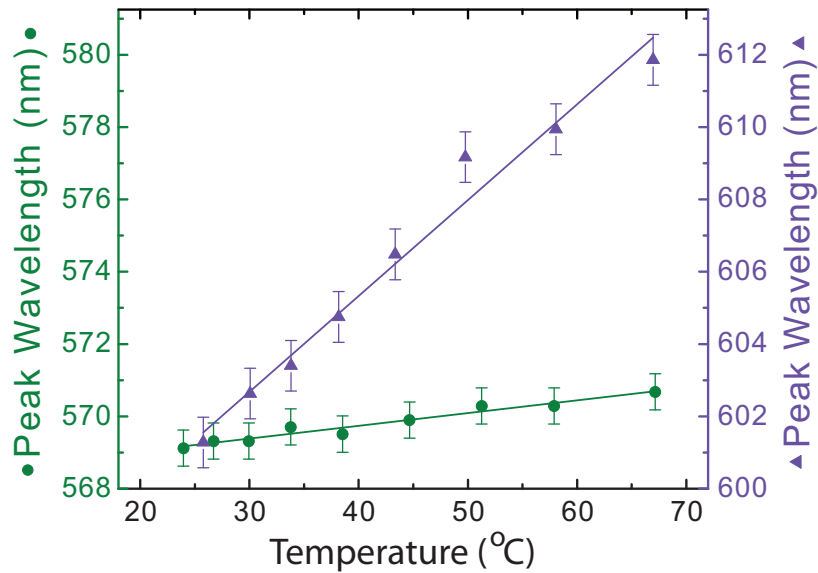


Fig. 3. The peak lasing wavelength as a function of temperature for two DBR lasers made by laminating an R6G-doped Lotador cavity between 128-layer films of alternating THV/EO (right, blue triangles) and PS/PMMA (left, green circles). The lines in both graphs are the linear fits the experimental data. Note that the right and left axes are drawn to the same scale but over slightly shifted spectral regions.

3.2. DBR lasers

The first DBR laser studied is that of a $\sim 30\mu\text{m}$ layer of Lotador confined between two 128-layer reflectors made from alternating layers of THV and EO, all of which are elastomeric, as previously described, but then placed between rigid glass coverslips. The peak lasing wavelength is plotted with respect to temperature in Fig. 3(left axis). The second DBR laser, a $\sim 30\mu\text{m}$ dye-doped Lotador gain medium between 128-layer PS/PMMA reflectors, also between glass coverslips, resulted in the plot of peak lasing wavelength as a function of temperature shown in Fig. 3 (right axis). The emission wavelength and wavelength temperature coefficient for both pinned DBR laser types are given in Table 1.

3.3. Thermo-optic and thermal strain characterization

The thermo-optic coefficients and thermal strain coefficients used to model the laser wavelength temperature dependence are given in Table 2. The thermo-optic coefficients, i.e., the temperature dependence of the refractive indices, for most of the constituent polymers were

Table 1. Thermo-spectral emission shifts ($\times 10^{-4}/^{\circ}\text{C}$)

Laser type	Center material	Reflector material	$(1/\lambda_e)d\lambda_e/dT$
Defect DFB	THV	THV/SAN25	2.33 ± 0.17
Defect DFB	SAN25	THV/SAN25	1.68 ± 0.17
Pinned DBR	Lotador	THV/EO	6.00 ± 0.50
Pinned DBR	Lotador	PS/PMMA	0.61 ± 0.29

Table 2. Thickness (L) and Refractive Index (n) Temperature Dependence ($\times 10^{-4}/^{\circ}\text{C}$)

Material	$(1/L)dL/dT$	dn/dT
THV	$2.14 \pm 0.08^{\S b}$	$-2.63 \pm 0.24^{\ddagger b}$
SAN25	$0.66 \pm 0.01^{\dagger}$	$-1.28 \pm 0.26^{\ddagger b}$
PMMA	0.65^{\diamond}	$-1.40 \pm 0.1^{\ddagger \#}$
PS	$0.73 \pm 0.13^{\# \dagger}$	$-1.4 \pm 0.1^{\ddagger}$
EO	$5.1 \pm 2.0^{\# \dagger}$	$-3.6 \pm 0.5^{\ddagger}$
glass substrate	< 0.1	

\ddagger Ellipsometry \S Interferometry b Defect spectrum fits
 $\#$ Grating method \dagger Ref. [12] $\#$ Ref. [13]
 \diamond Ref. [14] \diamond Ref. [15]

first measured using a Horiba Uvisel DUV-NIR spectroscopic ellipsometer for which the initial fits were refined through fits to the spectral data. Where possible, these values are also compared with values found in the literature. To perform these measurements, thin monoliths were spin-coated on silicon wafers and the measurements were performed with a probe beam at 70° from the direction normal to the substrate. Slow temperature drifts and calibration issues as well as difficulties in the optimization of multi-parameter refractive models are the leading contributions to the uncertainties.

The linear thermal expansion coefficients were measured for monoliths of most of the constituent materials. In addition to measuring the thickness changes directly through temperature dependent profilometry, we also measured thermal expansion coefficients using Fabry Perot interferometry or by diffraction from embossed gratings on the surfaces of the films. For example, the thermal expansion coefficient of THV (and other monoliths) was measured by pinning two ‘pillars’ $< 50\mu\text{m}$ high of the monolith films as thermally tunable spacers between mirrored surfaces forming an air-gapped Fabry-Perot interferometer. Using a 632.8nm HeNe laser, we monitored the fringes during heating to determine the thermal expansion of the pillars. Note that these pillars were thin enough and affixed well enough that their expansion parallel to the mirrored surfaces was mechanically pinned. Because the mirrored surfaces were gold sputtered on glass, which had a comparatively negligible thermal expansion, the measured thermal expansion in the cavity length was effectively a measure of the volumetric thermal expansion of the polymers. Additionally, the cavity was only lightly mechanically loaded for geometrical rigidity. Because THV loses stiffness when heated, the applied compressional force on the cavity may reduce the overall expansivity of THV [11], indicating that this technique may underreport the volumetric thermal expansivity.

4. Modeling and Discussion

The physical parameters contributing to any laser’s wavelength temperature dependence are its gain envelope shift and the combined effects of thermal strain and index change of the passive optical components that comprise the laser cavity. In multilayer laser films with a broad gain envelope the “optical geometry” (i.e., the list of layer optical thicknesses) is typically the dominant effect that selects the laser’s wavelength. Indeed, wavelength tunings via stretching and terracing the DFB and DBR lasers of Refs. [4,5] make the case for the significance of structure as compared to shifts in the gain envelope abundantly clear for the lasers studied in this report

(compare with Chua, *et al.* [16]). This dependence on structure in turn implies that simple linear optical models based with the thermal expansivities and thermo-optic coefficients of their constituent layers should both qualitatively and quantitatively capture the relevant phenomena reported above.

Below we test this assertion using as inputs only the gross structural morphology of each of the laser types studied here and the measured thermal and optical properties of the constituent polymers as detailed in Table 2. Note, however, that in our modeling, we have modified the starting thermal expansion coefficients given in Table 2 in the DFB films to account for the relative pinning of the softer of the two polymers by constraining its expansion in the plane to the expansion of the other polymer and, in the case of the DBR lasers, to account for the pinning of the multilayer polymer films to the much less thermally expansive glass coverslips. Thus, we assumed that the THV layers in the DFB laser films were constrained to expand in the plane only as much as the more rigid SAN25 layers, leading to a nearly three times greater thermal expansivity for the THV layer thicknesses. Similarly, all of the DBR films were constrained by the glass coverslips to not expand appreciably in the plane, leading to enhanced thermal expansion of the thickness of the films. We saw no evidence of delamination of the films during any of our experiments.

First, qualitatively and in gross effect, thermal expansion causes the spectral features of the multilayer interference to shift toward longer wavelengths. However, each constituent polymer listed in Table 2 has a negative thermo-optic coefficient, which, taken by itself, would shift the spectral features to shorter wavelengths. With both effects taken concurrently for these materials, experiment and linear transport models using the inputs from Table 2 indicate that thermal expansion typically dominates the index changes for our materials and thus the optical path length (and bands and band features) shifts to longer wavelength with increasing temperature.

Both experiment and linear transport modeling, however, indicate that this redshift with temperature is not uniform across the reflection band, but is greater near the long wavelength band edge. To model this effect, we first assume perfect layer thicknesses except for the center layer, which is adjusted to a thickness that creates a band defect at the desired location near the right or left edge of the reflection band. We used a least squares fitting routine to obtain theoretical parameters (thermal expansion and thermo-optic coefficients) by fitting the calculated shifts in spectral features (band edge and defect shifts) from transfer matrix methods to those obtained via experiments. We used values obtained from ellipsometry and interferometry measurements as the initial parameters. To get a unique fit, we held the thermal expansion coefficient of SAN25 (given in Ref. [12]) constant and optimized the relative thermal shifts using the other three parameters (thermal expansion and thermo-optic coefficients of THV and thermo-optic coefficient of SAN25). The fitting values, listed in Table 2, are in good agreement with the literature and independent monolith measurements. In these binary films, optical transport near the short wavelength band edge corresponds to the light spending more time in the high index material (which here has a smaller temperature coefficient) and vice-versa at the long wavelength band edge where transport is dominated by the wave's presence in the low index material (which here has a higher temperature coefficient) [17]. Our modeling bears out this relationship as well, indicating that, for these materials, the ratio of the thermo-spectral band edge shifts is predicted to be $1.6 (\pm 0.1)$, very close to our experimentally measured ratio for the band edges. (The measured short wavelength band edge shifts as $(1/\lambda)(d\lambda/dT) = (1.51 \pm 0.16) \times 10^{-4}/^\circ\text{C}$, and the measured long wavelength band edge shifts as $(1/\lambda)(d\lambda/dT) = (2.35 \pm 0.25) \times 10^{-4}/^\circ\text{C}$.)

The defect DFB lasers exhibit low-threshold, coherent emission at the reflection band defect's spectral location [5, 18]. Therefore, simply recording the shift in the reflection band defect in simulations with linear coefficients as a function of temperature yields the defect DFB laser's temperature coefficient. The defect's position in the reflection band is a function of the optical

phase accumulated in the central layer [19,20]. Thus, each defect DFB laser's wavelength temperature coefficient depends on the temperature shift of the reflection band, the initial spectral location of the defect within that band, and the properties of the material used for the center defect layer.

Calculations of the energy density during steady state linear transport in these defect DFB's indicate that the light spends more time in the centermost region of the film [21]. In keeping with the description above, as one adds thickness (and thus phase accumulation) to the center layer, the resulting band defect initially moves towards longer wavelength as the portion of the time it spends in the lower index material increases. Quantitatively, linear transfer matrix modeling confirms that each defect DFB laser's temperature coefficient is strongly dependent on where in the reflection band the defect occurs [5]. This result is relevant because our experiments show that spectral defects from THV-folded systems appear near the long-wavelength edge of the reflection band, whereas the defects from SAN25-folded systems are closer to the short-wavelength edge of the reflection, artifacts of layer thickness deviations in our films embedded during the co-extrusion process [10].

Numerical simulations of the location of the defect relative to the band edges show that the ratio of the temperature coefficients $(1/\lambda)(d\lambda/dT)$ from the long wavelength band edge over the short wavelength band edge can be as high as 1.7 (± 1). This ratio is consistent with the results shown in Table 1 and with the locations of the individual band edges for our THV and SAN25 centered films. Further, in as much as there is a difference between this ratio and that of the individual band edges, it may be simply understood in terms of the 'persistence' of the light in the center element of the stack for the defect mode (as indicated by the energy density calculations) compared with the nearly evanescent state at the band edges, which do not preferentially sample the center layer.

The DBR data (Fig. 3) qualitatively reinforces these lessons. While the complexities in this case (whose central gain layer, at ~ 30 microns, is significantly wider than the mirrors, each about 7 microns) make a quantitative theoretical model of the laser wavelength temperature coefficient more daunting, the difference between the two DBR cases in Fig. 3 provides evidence that it is the DBR mirror temperature coefficient and not the central layer's expansion that dominates the laser's temperature coefficient.

Analytical models as simple as a linear optical three layer dielectric (with gain in the middle element and thin, large index 'mirrors' on each end) also emphasize the role that the mirrors' transmission features have on the density of states, thereby both increasing the gain and reducing the cavity mode spacing. Thus, although the penetration into the mirrors is only about 4 microns [22] and cannot account, by itself, for the data in Fig. 3, it is the tight association of the transmission features of the mirrors with lasing that force the DBR lasers' temperature coefficients to follow those of the DBR mirrors alone. This result is consistent with the conclusion from Ref. [4], where the DBR lasing wavelength was closely tied to that of transmission defects.

5. Conclusions

The temperature tunability and stability of all-polymer DBR and defect DFB laser films have been studied for select materials. We found that for DBR laser films, the temperature dependence of the laser wavelength was dominated by the mirrors and not the (much larger) gain medium. Thus, cavities with PS/PMMA (low temperature coefficient) reflectors make DBR lasers that are temperature stable. The output wavelength of DBR lasers with the very same gain element but with EO/THV reflectors (two elastomers with large thermal expansions) have a large temperature coefficient, indicating a >10 nm tuning range across a 30° temperature shift. Similarly, defect DFB laser's thermal coefficients are found to depend mainly on the location

of the reflection band defect and the relative index of refraction of the center layer.

Significantly, a simple optical transport model based on transfer matrices quantitatively reproduces the observed defect DFB laser behavior, and qualitatively illuminates the DBR laser temperature dependence. In both cases, experiments and simulations indicate that the temperature coefficients of the multilayer mirrors are paramount in determining the temperature coefficient of the lasing wavelength. This work confirms that other factors that one might have expected to have contributed to the temperature coefficient, such as gain envelope temperature dependence, thermal strain of the centermost fold layer (defect DFB) and thermal strain of the gain medium (DBR) are less important.

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